
5.5V、1.5A、1.5MHZ Synchronous Step-Down Converter H9008

General Description

The H9008 is a high-efficiency monolithic synchronous buck regulator using a constant frequency, current mode architecture. The device is available in an adjustable version. Supply current with no load is 40uA and drops to <1uA in shutdown. The 2.5V to 5.5V input voltage range makes the H9008 ideally suited for single Li-Ion battery powered applications. 100% duty cycle provides low dropout operation, extending battery life in portable systems. PWM/PFM mode operation provides very low output ripple voltage for noise sensitive applications. Switching frequency is internally set at 1.5MHz, allowing the use of small surface mount inductors and capacitors. Low output voltages are easily supported with the 0.6V feedback reference voltage. The H9008 requires a minimal number of readily available, external components and is available in a space saving SOT23-5 package.



SOP23-5

Features

- High Efficiency: Up to 96%
- 1.5A Continuous Output Current
- 2.5V to 5.5V Input Voltage Range
- 1.5MHz Switching Frequency
- No Schottky Diode Required
- Output Adjustable from 0.6V
- Built-in Short Protection
- Built-in Over Voltage Protection
- Built-in Over Current Limit
- Over temperature Protected
- PFM Mode for High Efficiency in Light Load
- Low Quiescent Current: 40μA
- Available in SOT23-5 package
- -40° C to +85° C Temperature Range
- Internal Soft-Start

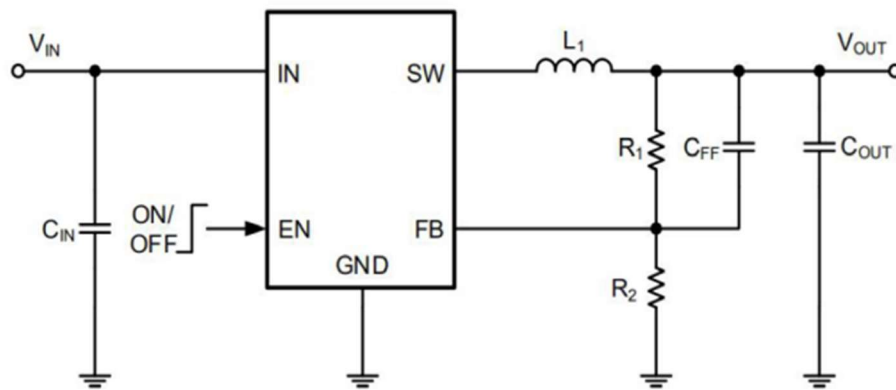
Applications

- Cellular and Smart Phones
- Wireless and DSL Modems
- PDAs
- Portable Instruments
- Digital Still and Video Cameras
- PC Cards

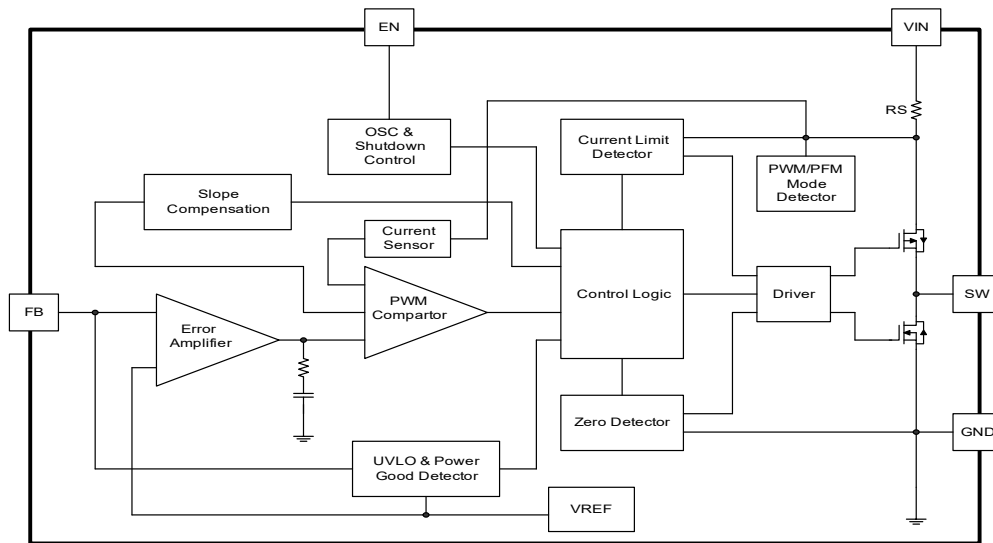
Order information

Product model	Package	Manner of packing	Minimum packing quantity
H9008-SOT23-5	SOT23-5	reel	3000

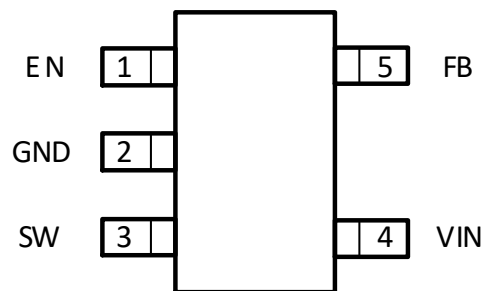
Basic application circuit



Functional Block Diagram



Pin Assignm



SOT23-5(Top View)

Table1 H9008 series (SOT23-5 PKG)

PIN	NAME	FUNCTION
1	EN	Chip Enable Pin. Drive EN above 1.2V to turn on the part. Drive EN below 0.6V to turn it off. Do not leave EN floating.
2	GND	Ground Pin
3	SW	Power Switch Output. It is the switch node connection to Inductor. This pin connects to the drains of the internal P-ch and N-ch MOSFET switches.
4	VIN	Power Supply Input. Must be closely decoupled to GND with a 10 μ F or greater ceramic capacitor.
5	FB	Output Voltage Feedback Pin. An internal resistive divider divides the output voltage down for comparison to the internal reference voltage.

Absolute Maximum Ratings (Note 1)

Input Supply Voltage	-0.3V to 6.0V
Operating Temperature Range	-40°C to +85°C
EN, FB Voltages	-0.3V to 6.0V
Junction Temperature ^(Note2)	125°C
SW Voltage	-0.3V to (Vin+0.3V)
Storage Temperature Range	-55°C to 150°C
Peak SW Sink and Source Current	2 A
Lead Temperature(Soldering,10s)	+260°C

Electrical Characteristics (Note 3)

Parameter	Conditions	Min.	Typ.	Max.	Unit
Input Voltage Range		2.5		5.5	V
Supply Current (Quiescent)	VEN =3.0V		40	80	μA
Supply Current (Shutdown)	VEN =0 or EN = GND		0.1	1.0	μA
Feedback Voltage		0.585	0.600	0.615	V
High-Side Switch On-Resistance	ISW=100mA		300		mΩ
Low-Side Switch On-Resistance	ISW=-100mA		200		mΩ
Upper Switch Current Limit		2			A
Over Voltage Protection Threshold			6		V
Switching Frequency			1.5		MHz
EN Rising Threshold		1.2			V
EN Falling Threshold				0.6	V
EN Threshold Hysteresis			100		mV
Under-Voltage Lockout Threshold	Wake up VIN Voltage		2.3	2.45	V
	Shutdown VIN Voltage	1.75	1.9		V
	Hysteresis VIN voltage		400		mV
Soft Start			1		mS
Thermal Shutdown			160		°C
Thermal Hysteresis			30		°C

Noot1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Noot2: TJ is calculated from the ambient temperature TA and power dissipation PD according to the following formula:

$$T_J = T_A + (P_D) \times (250^\circ \text{ C/W}).$$

Noot3: 100% production test at +25° C. Specifications over the temperature range are guaranteed by design and characterization.

Functions Description

Internal Regulator

The H9008 is a current mode step down DC/DC converter that provides excellent transient response with no extra external compensation components. This device contains an internal, low resistance, high voltage power MOSFET, and operates at a high 1.5MHz operating frequency to ensure a compact, high efficiency design with excellent AC and DC performance.

Error Amplifier

The error amplifier compares the FB pin voltage with the internal FB reference (VFB) and outputs a current proportional to the difference between the two. This output current is then used to charge or discharge the internal compensation network, which is used to control the power MOSFET current. The optimized internal compensation network minimizes the external component counts and simplifies the control loop design.

Under-Voltage Lockout (UVLO)

Under-voltage lockout (UVLO) protects the chip from operating at an insufficient supply voltage. UVLO protection monitors the internal regulator voltage. When the voltage is lower than UVLO threshold voltage, the device is shut off. When the voltage is higher than UVLO threshold voltage, the device is enabled again.

Thermal Shutdown

Thermal shutdown prevents the chip from operating at exceedingly high temperatures. When the silicon die temperature exceeds 160°C, it shuts down the whole chip. When the temperature falls below its lower threshold (Typ. 130°C) the chip is enabled again.

Internal Soft-Start

The soft-start is implemented to prevent the converter output voltage from overshooting during startup. When the chip starts, the internal circuitry generates a soft-start voltage (SS) ramping up from 0V to 0.6V. When it is lower than the internal reference (REF), SS overrides REF so the error amplifier uses SS as the reference. When SS is higher than REF, REF regains control. The SS time is internally to 1ms.

Startup and Shutdown

If both V_{IN} and V_{EN} are higher than their appropriate thresholds, the chip starts. The reference block starts first, generating stable reference voltage and currents, and then the internal regulator is enabled. The regulator provides stable supply for the remaining circuitries. Three events can shut down the chip: V_{EN} low, V_{IN} low and thermal shutdown. In the shutdown procedure, the signaling path is first blocked to avoid any fault triggering. The comp voltage and the internal supply rail are then pulled down. The floating driver is not subject to this shutdown command.

Applications Information

Setting the Output Voltage

H9008 require an input capacitor, an output capacitor and an inductor. These components are critical to the performance of the device. H9008 are internally compensated and do not require external components to achieve stable operation. The output voltage can be programmed by resistor divider.

$$V_{OUT} = V_{FB} \times \frac{R1 + R2}{R2}$$

When sizing R2, in order to achieve low current consumption and acceptable noise sensitivity, use a maximum of 200kΩ for R2. Larger currents through R2 improve noise sensitivity and output voltage accuracy but increase current consumption.

VOUT(V)	R1(KΩ)	R2(KΩ)	L1(μH)	CIN(μF)	COUT(μF)	CFF (pF) Opt.
1.0	66.67	100	2.2	22	22×2	CFF Chapter
1.05	75.00	100	2.2	22	22×2	CFF Chapter
1.2	100.00	100	2.2	22	22×2	CFF Chapter
1.5	150.00	100	2.2	22	22×2	CFF Chapter
1.8	200.00	100	3.3	22	22×2	CFF Chapter
2.5	316.67	100	3.3	22	22×2	CFF Chapter
3.3	450.00	100	4.7	22	22×2	CFF Chapter

All the external components are the suggested values, the final values are based on the application testing results.

Selecting the Inductor

The recommended inductor values are shown in the Application Diagram. It is important to guarantee the inductor core does not saturate during any foreseeable operational situation. The inductor should be rated to handle the maximum inductor peak current: Care should be taken when reviewing the different saturation current ratings that are specified by different manufacturers. Saturation current ratings are typically specified at 25 °C , so ratings at maximum ambient temperature of the application should be requested from the manufacturer. The inductor value can be calculated with:

$$L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times \Delta I_L \times F_{OSC}}$$

Where ΔIL is the inductor ripple current. Choose inductor ripple current to be approximately 30% to 40% of the maximum load current. The maximum inductor peak current can be estimated as:

$$I_{L(MAX)} = I_{LOAD} + \frac{\Delta I_L}{2}$$

Under light load conditions below 100mA, larger inductance is recommended for improved efficiency. Larger inductances lead to smaller ripple currents and voltages, but they also have larger physical dimensions, lower saturation currents and higher linear impedance. Therefore, the

choice of inductance should be compromised according to the specific application.

Selecting the Input Capacitor

The input current to the step-down converter is discontinuous and therefore requires a capacitor to supply AC current to the step-down converter while maintaining the DC input voltage. For a better performance, use ceramic capacitors placed as close to VIN as possible and a 0.1μF input capacitor to filter out high frequency interference is recommended. Capacitors with X5R and X7R ceramic dielectrics are recommended because they are stable with temperature fluctuations. The capacitors must also have a ripple current rating greater than the maximum input ripple current of the converter. The input ripple current can be estimated with Equation:

$$I_{CIN} = I_{OUT} \times \sqrt{\frac{V_{OUT}}{V_{IN}} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right)}$$

From the above equation, it can be concluded that the input ripple current reaches its maximum at VIN=2VOUT where

$$I_{CIN} = \frac{I_{OUT}}{2}$$

.For simplification, choose an input capacitor with an RMS current rating greater than half of the maximum load current.

The input capacitance value determines the input voltage ripple of the converter. If there is an input voltage ripple requirement in the system, choose the input capacitor that meets the specification. The input voltage ripple can be estimate with Equation:

$$\Delta V_{IN} = \frac{I_{OUT}}{F_{OSC} \times C_{IN}} \times \frac{V_{OUT}}{V_{IN}} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right)$$

Similarly, when VIN=2VOUT, input voltage ripple reaches its maximum of

Selecting the Output Capacitor

An output capacitor is required to maintain the DC output voltage. The output voltage ripple can be estimated with Equation:

$$\Delta V_{OUT} = \frac{V_{OUT}}{F_{OSC} \times L} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right) \times \left(R_{ESR} + \frac{1}{8 \times F_{OSC} \times C_{OUT}}\right)$$

There are some differences between different types of capacitors. In the case of ceramic capacitors, the impedance at the switching frequency is dominated by the capacitance. The output voltage ripple is mainly caused by the capacitance. For simplification, the output voltage ripple can be estimated with Equation:

$$\Delta V_{OUT} = \frac{V_{OUT}}{8 \times F_{OSC}^2 \times L \times C_{OUT}} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right)$$

A larger output capacitor can achieve a better load transient response, but the maximum output capacitor limitation should also be considered in the design application. If the output capacitor

value is too high, the output voltage will not be able to reach the design value during the soft-start time and will fail to regulate. The maximum output capacitor value (C_{OUT_MAX}) can be limited approximately with Equation:

$$C_{OUT_MAX} = (I_{LIM_AVG} - I_{OUT}) \times T_{SS} / V_{OUT}$$

Where I_{LIM_AVG} is the average start-up current during the soft-start period, and T_{SS} is the soft-start time. On the other hand, special attention should be paid when selecting these components. The DC bias of these capacitors can result in a capacitance value that falls below the minimum value given in the recommended capacitor specifications table.

The ceramic capacitor's actual capacitance can vary with temperature. The capacitor type X7R, which operates over a temperature range of -55°C to $+125^{\circ}\text{C}$, will only vary the capacitance to within $\pm 15\%$. The capacitor type X5R has a similar tolerance over a reduced temperature range of -55°C to $+85^{\circ}\text{C}$. Many large value ceramic capacitors, larger than $1\mu\text{F}$ are manufactured with Z5U or Y5V temperature characteristics. Their capacitance can drop by more than 50% as the temperature varies from 25°C to 85°C . Therefore, X5R or X7R is recommended over Z5U and Y5V in applications where the ambient temperature will change significantly above or below 25°C .

Feed-Forward Capacitor (CFF)

H9008 has internal loop compensation, so adding CFF is optional. Specifically, for specific applications, if necessary, consider whether to add feed-forward capacitors according to the situation.

The use of a feed-forward capacitor (CFF) in the feedback network is to improve the transient response or higher phase margin. For optimizing the feed-forward capacitor, knowing the cross frequency is the first thing. The cross frequency (or the converter bandwidth) can be determined by using a network analyzer. When getting the cross frequency with no feed-forward capacitor identified, the value of feed-forward capacitor (CFF) can be calculated with the following equation:

$$C_{FF} = \frac{1}{2\pi \times F_{CROSS}} \times \sqrt{\frac{1}{R1} \times \left(\frac{1}{R1} + \frac{1}{R2}\right)}$$

Where F_{CROSS} is the cross frequency.

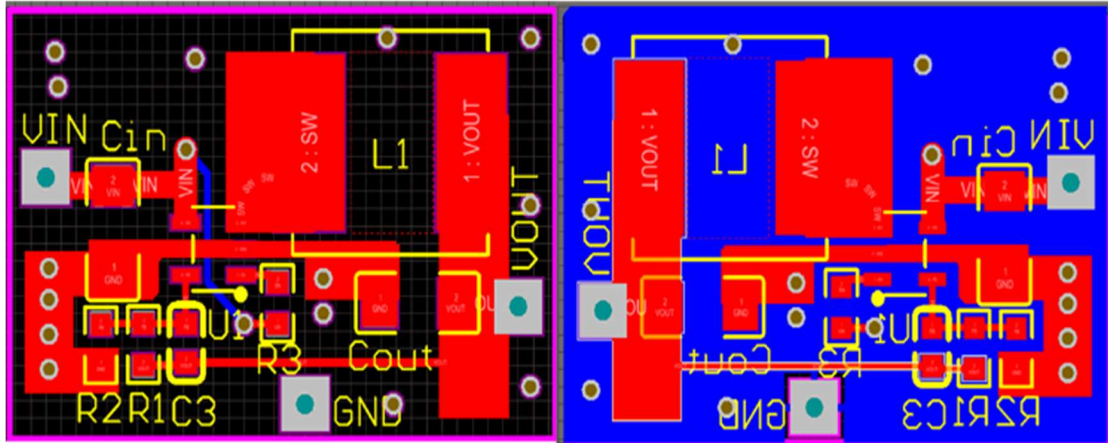
To reduce transient ripple, the feed-forward capacitor value can be increased to push the cross frequency to higher region. Although this can improve transient response, it also decreases phase margin and cause more ringing. In the other hand, if more phase margin is desired, the feed-forward capacitor value can be decreased to push the cross frequency to lower region.

PC Board Layout Consideration

PCB layout is very important to achieve stable operation. It is highly recommended to duplicate EVB layout for optimum performance. If change is necessary, please follow these guidelines for reference.

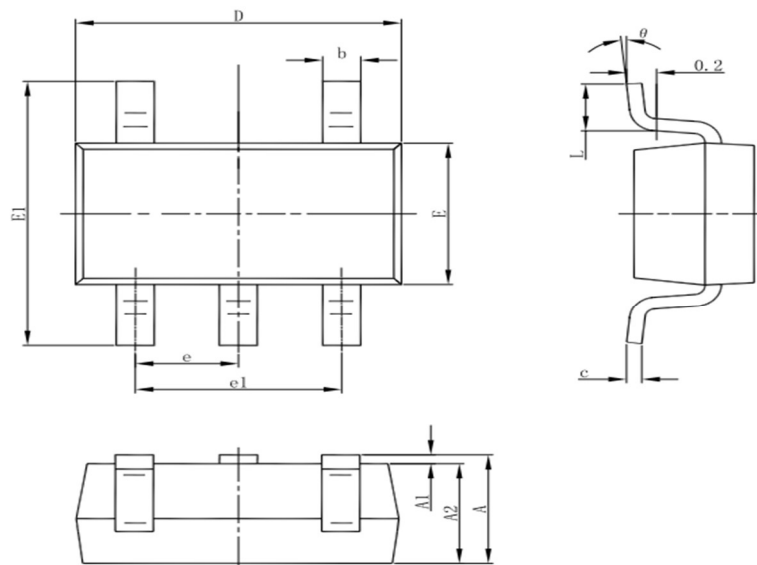
1. Keep the path of switching current short and minimize the loop area formed by Input capacitor, high-side MOSFET and low-side MOSFET.
2. Bypass ceramic capacitors are suggested to be put close to the VIN Pin.

3. Ensure all feedback connections are short and direct. Place the feedback resistors and compensation components as close to the chip as possible.
4. VOUT, SW away from sensitive analog areas such as FB. Connect IN, SW, and especially GND respectively to a large copper area to cool the chip to improve thermal performance and long-term reliability.



Package Description

SOT23-5 Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.852	3.020	0.111	0.119

E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

Special Version

The company reserves the right of final interpretation of this specification.

Version Change Description

Versions: V1.7

Writer: Liu Hang

Time: 2021.09.30

Amendant record:

- 1.Re-typesetting the manual and checking some data